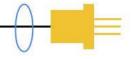


The Friend of Lasers



850nm 200mW VCSEL Diode in 2016 Package

Part No. VC20A-850H200A (Substrate AIN) | VC20C-850H200A (Substrate CuAg)

Features

- 2016 package
- Good thermal conduction
- Oxide isolation technology
- Low threshold current
- High reliability and easy to collimate
- 200mW 850nm VCSEL @ 350mA

Applications

- Proximity sensor
- 3D sensor
- IR illumination
- Medical application
- Lidar



Substrate AIN, Package 2016



Substrate CuAg, Package 2016

Specifications

Absolute Maximum Ratings								
Parameters	Symbol	Rating	Unit	Conditions				
Case Operating Temperature	Тор	op -40 to 60						
Storage Temperature	Tstg	-40 to 105	°C					
Reflow Soldering Temperature	Tsol	260	°C	10 seconds				
Reverse Voltage	Vr	5	V					
Maximum Continuous Current	Imax	0.7	A					
ESD Exposure (Human Body) Model	ESD	2K	V					

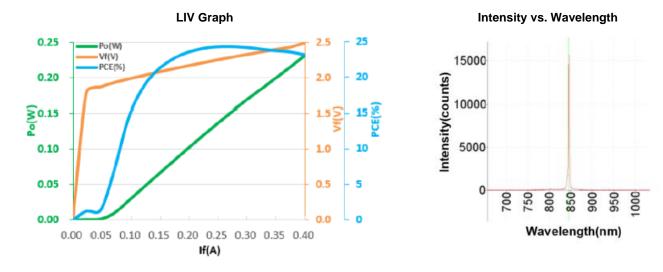
Notes:

- Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or other conditions above those indicated in the operations section for expanded periods of time may affect reliability.
- In its maximum rating diode laser operation could damage its performance or cause potential safety hazard such as equipment failure.
- Electrostatic discharge is the main reason for laser fault of the diode. Take effective precautions against ESD. When dealing with laser diodes, use wrist strap, grounding work surface and strict antistatic technology.

Electro-Optical Characteristics (T _{op} =25°C)								
Parameters	Symbol	Min.	Typ.	Max.	Unit	Conditions		
Optical Output Power	Po	-	200	-	mW	I _F =350mA		
Threshold Current	Ith	-	50	-	mA			
Slope Efficiency	η	-	0.67	-	mW/mA	Po=200mW		
Power Conversion Efficiency	PCE	-	24	-	%	IF=350mA		
Peak Wavelength	λρ	840	850	860	nm	I _F =350mA		
Laser Forward Voltage	VF	2.3	2.4	2.5	V	I _F =350mA		
Series Resistance	Rs	6.57	6.89	7.14	Ohm	I _F =350mA		
Beam Angle	θ	-	20	25	Deg	I _F =350mA		
Wavelength Temperature Drift	Δλρ/ ΔΤ	-	-	0.07	nm/°C	IF=350mA		
Soldering Temperature	Tsol			260	°C	10 seconds		
Substrate	AIN; CuAg							



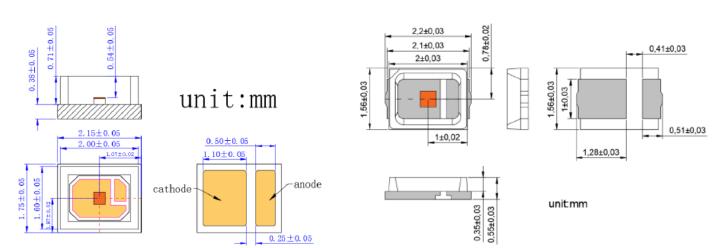
Typical Characteristics



Outline Dimensions (unit: mm)

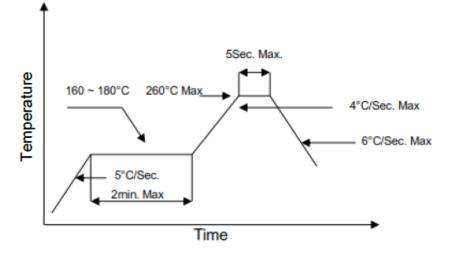
Substrate AIN, Package 2016

Substrate CuAg, Package 2016





SMT Reflow Soldering Curve



Note: Reflow soldering can be operated only one time. During the temperature ramp-up, no forces may be exerted on the LD which would deform or damage them. After soldering is completed, please do not process until the product temperature ramps down to room temperature.

Additional Notes

- 1. Please use solder paste to cure the laser diode.
- 2. Please make sure that the heat of VCSEL diode has been completely conducted to metal shell to avoid affecting the optical power output.
- 3. This VCSEL diode can be only used in constant voltage and current.
- 4. Please do not aim the laser at people or animals.
- 5. You may observe the laser spot through an image monitoring equipment.
- 6. Please do not touch VCSEL diode surface by naked hands or squeeze the sealant on VCSEL diode surface. It may cause wrong optical angle and distorted laser spot, and even damage the VCSEL diode.
- 7. Please use ceramic suction nozzle to absorb the VCSEL diode, so as to avoid VCSEL diode sticking to the nozzle.
- 8. Please add a 0.02s blowing action after locating the laser diode to aluminum substrate.
- 9. Specifications are subject to change without notice.